

TEST BOOKLET No.

146

#### TEST FOR POST GRADUATE PROGRAMMES

#### **ELECTRONIC SCIENCE**

Time: 2 Hours

Maximum Marks: 450

#### INSTRUCTIONS TO CANDIDATES

- 1. You are provided with a Test Booklet and an Optical Mark Reader (OMR) Answer Sheet to mark your responses. Do not soil the Answer Sheet. Read carefully all the instructions given on the Answer Sheet.
- 2. Write your Roll Number in the space provided on the top of this page.
- 3. Also write your Roll Number, Test Code, and Test Subject in the columns provided for the same on the Answer Sheet. Darken the appropriate bubbles with a Ball Point Pen.
- 4. The paper consists of 150 objective type questions. All questions carry equal marks.
- 5. Each question has four alternative responses marked A, B, C and D and you have to darken the bubble corresponding to the correct response fully by a Ball Point Pen as indicated in the example shown on the Answer Sheet.
- 6. Each correct answer carries 3 marks and each wrong answer carries 1 minus mark.
- Space for rough work is provided at the end of this Test Booklet.
- 8. You should return the Answer Sheet to the Invigilator before you leave the examination hall. However, you can retain the Test Booklet.
- 9. Every precaution has been taken to avoid errors in the Test Booklet. In the event of any such unforeseen happening, the same may be brought to the notice of the Observer/Chief Superintendent in writing. Suitable remedial measures will be taken at the time of evaluation, if necessary.



### ELECTRONIC SCIENCE

1.	An intrinsic semiconductor at the absolute zero temperature
10	(A) behaves like a metallic conductor
	(B) behaves like an insulator
	(C) has a large number of holes
	(D) has a large number of electrons
2.	At room temperature, the current in an intrinsic semiconductor is due
	to
	(A) Holes (B) Electronics
	(C) Ions (D) Holes and Electronics
3.	In an n-type semiconductor, as temperature T increases, the Fermi level $\mathrm{E}_{\mathrm{F}}$
	(A) moves towards conduction band
	(B) moves towards middle of forbidden energy gap
	(C) does not vary
	(D) may or may not shift depending upon the concentration of
	donor atoms
4.	Ratings on a capacitor are given 25µF, 12 V. Also a minus sign is written near one of its terminals. The capacitor is
	(A) Mica capacitor (B) Ceramic capacitor
	(C) Electrolytic capacitor (D) Paper capacitor
-	Which of the following doping will produce a p-type semiconductor?
5.	
	(A) Germanium with phosphorus (B) Silicon with germanium
	(C) Germanium with antimony (D) Silicon with indium
6.	Which of the following is an active device?
	(A) An electric bulb (B) A resistor
	(C) A.BJT (D) A transformer

7.	A virtua	A virtual ground					
	(A) (B) (C) (D)	is ground for current					
8.	The pro	ogram used to convert mnemo	onics t	o machine code is			
	(A) (C)	Fortan Assembler	(B) (D)	C++ Opcode			
9.		istor is said to be in	reg	gion when both the junctions			
	(A)	active	(B)	saturation			
	(C)		(D)	passive			
10.	Loading	g effect of a voltmeter can be	reduc	ed by			
	(A) (B) (C) (D)	increasing the load resistant increasing the internal resist decreasing the load resistant decreasing the internal resist	tance o	*			
11.	The hig	hest voltage gain can be obta	ined f	rom which of the following?			
	(A) (C)	CB configuration CC configuration	(B) (D)	CE configuration All of the above			
12.	Power g	gain of emitter follower usua	lly is				
	(A) (C)	Unity More than one	(B) (D)	Less than one None of the above			
13.	Ripple 1	factor of a half wave rectifier	ris				
	(A) (C)	more than two less than one	(B) (D)	more than one zero			



14.	The sel	lf-destruction of an unsta ture is called	abilised t	ransistor due to rise in		
	(4)	Thormal ninaway	(B) I	Heat dissipation		
		Thermal runaway	( )	Q-factor		
	(C)	Thermocouple	(12)	<b>2</b>		
15.	A Bark-	Hausen criterion for oscilla	ator stabili	ty is		
	(4)	$A\beta = 0$	(B) A	$A\beta = 1$		
	(C)	$-A\beta = 1$	(D) -	$A\beta = 1$ $A\beta = 0$		
	(C)	-Ap - 1	(2)			
16.	In Freq time bu	uency Division Multiplexit each occupies	ng, all sig	gnals are sent at the same ency band.		
×	(4)	150	(B) d	lifferent		
	(A)	same	( )	None of the above		
	(C)	either (A) or (B)	(D) 1	tone of the above		
17.	In JFET operating above pinch-off voltage, the					
	(A)	ID remains practically cor	istant			
	(B)					
		I <sub>D</sub> increases rapidly				
	(D)	depletion region becomes	smaller			
	(2)					
18.	What is	s the binary equivalent of the	ne decima	l number 465?		
	(A)	111010001	(B)	110110000		
	(C)	111010000	(D)	111100000		
	(0)	111010000	(2)			
19.	How m	any Flip-Flops are require	d for mod	l–16 counter?		
	(4)		(B)	6		
	(A)	3	(D)	1 1311 (24)		
	(C)	3	(D)	That is called		
20.	EPRO	M contents can be erased b	y exposir	ng it to		
		and the state of t	(D)	in from all nave		
	(A)	ultraviolet rays	(B)	infrared rays		
	(C)	burst of microwaves	(D)	intense heat radiations		

21.	A ring counter consisting of five Flip-Flops will have			
			(B)	10 states
	(A)	5 states		infinite states
	(C)	32 states	(D)	
22.	The 2's	complement of the number	001001	1 is
LL.	1110 2 3			
	(A)	0101110	(B)	0111110
	(C)	0110010	(D)	1101101
23.	The gat	es required to build a half a	dder are	
	(A)	EX-OR gate and NOR gat	:e	361
	(B)		te	
	(C)	EX-OR gate and OR gate		
	(D)	Four NAND gates	•	
.24.		ode where all successive nor by single bit is	umbers	differ from their preceding
	(A)	Binary code	(B)	BCD
	(C)	Excess – 3	(D)	Gray
25.		input to T-flip-flop is 100 H flops in cascade is	Iz signa	l, the final output of the fourb
	(A)	1000 Hz	(B)	100 Hz
	(C)		(D)	
26.	The d	igital logic family which ha	s the lov	west propagation delay time is
	(A)	ECL	(B)	TTL
	(C)		(D)	
27.	The d	evice which changes from s	serial da	ta to parallel data is
	(A	) Counter	(B	) Multiplexer
	(C		(D	Ficitor
	, -	•	,	,



		D converter who of bits is	ose conver	sion 1	time is indep	endent of	the
(	(A)	Dual slope		(B)	Counter type		
	(C)		ion -	(D)	TO THE	proximatio	on
29. The	exc	ess 3 code of dec	cimal numbe	r 26 i	5		
	(A)	0100 1001		(B)	01011001		
	(C)	1000 1001		(D)	01001101		
0. Wh	ich (	of the following	nemories sto	ores th	ne most numbe	er of bits?	
(	(A)	5M×8 memory		(B)	1M ×16 men	nory	
	(C)			(D)	12M×1mem		
	200	al ICs, Schottky to	ransistors ar	e pre	ferred over no	rmal transi	stors
(	(A)	lower propagati	on delay			10000	
	B)	higher propagat					
(	(C)	lower power dis					
07	(D)	higher power di	ssipation				
2. The	acc	ess time of ROM	I using bipo	lar tra	insistors is abo	out	
(	(A)	1 sec		(B)	1 msec		
•		1 μsec		(D)	1 nsec		
3. Wh	ich i	s non resonant a					
(	(A)	Marconi		(B)	Rhombic	13	
		Yagi-Uda		(D)		OF S	
						E WOIL	On

34.	For a t	ransmission line terminate	ed in it	s characteristic impedance, ct?			
	which o	f the following statement is	incorre	CI!			
		<ul> <li>(A) It is a smooth line</li> <li>(B) The energy distribution between magnetic and electric field is not equal</li> </ul>					
	(C)	Standing wave does not ex	cist of now	er is maximum			
	(D)	Efficiency of transmission	or pow				
35.	Radiati	on resistance of a $\lambda/2$ dipole	eis	25			
	(A)	73 ohm	(B)	75 ohm .			
	(A)77A	120 π ohm	(D)	377 ohm			
36.	The do	minant mode of rectangular	wave g	uide is			
	(A)	TEII	(B)	$TM_{11}$			
		TE 01	(D)	TE <sub>10</sub>			
37.	Depth	of penetration in free space	is				
	(A)	α	(B)	1/α			
	(C)		(D)	∞			
38.	For a 3	00Ω antenna operating with	h 5A of	current, the radiated power is			
	(A)	7500 W	(B)	750 W			
		75 W	(D)	7500 mW			
39.	The lo	ower cut-off frequency of sions (3×4.5 cm) operating	a rectan g at 10 C	gular waveguide with inside			
	(A)	10 GHz	(B)	9 GHz			
0 2	(C)	10/9GHz	(D)	10/3GHz			
40.	How r	nany op-amps are required	to imple	ement this equation $V_0 = V_1$ ?			
	(A)	) Four	(B)	Three			
	(C)	Two	(D)	One			



41.	A difference between a passive filter and an active filter is that passive filter uses amplifier(s), but an active filter does not. This is					
	<ul> <li>(A) True</li> <li>(B) False</li> <li>(C) True in the case of Butter worth filter</li> <li>(D) True in the case of Chebyshev filters</li> </ul>					
42.	Higher band widths are possible in					
	<ul> <li>(A) mono mode step index fiber</li> <li>(B) multimode step index fiber</li> <li>(C) multimode graded index fiber</li> <li>(D) All of the above</li> </ul>					
43.	In modulation bandwidth doubling and carrier power wasted are avoided.					
	(A) AM (C) SSB (B) FM (D) DSBSC					
44.	In a communication system, the noise is most likely to affect the signal					
	(A) at the transmitter (B) in the channel (C) at the receiver (D) in the source					
45.	Bandwidth of FM					
	<ul> <li>(A) is greater than that of AM</li> <li>(B) is less than that of AM</li> <li>(C) is equal to that of AM</li> <li>(D) cannot predict</li> </ul>					
46.	Modems are used for carrying					
	<ul> <li>(A) digital data over digital line</li> <li>(B) digital data over analog line</li> <li>(C) analog data over analog line</li> <li>(D) analog data over digital line</li> </ul>					

47	<ol> <li>In standing wave pattern on a transmission line</li> </ol>				
	(E (C	voltage and current nodes voltage and current antine voltage nodes and current and voltage antinodes coi both (A) and (B)	ode coir	de scide odes as well as current nodes	
48.		h of the following is an nission?	advanta	age to use fiber optic data	
49.	(B) (C) (D)	Resistance to the data the Fast data transmission rate Low noise level All of the above	e		
42.	which	among the following is not	a featur	re of Op-amp?	
	(A)	High CMRR	(B)	High gain	
	(C)	Low output impedance	(D)	Low input impedance	
50.	<ol> <li>Avalanche break down not happens in</li> </ol>				
	(A)	Zener diode	(B)	Varactor diode	
	(C)	Junction diode		Both (B) and (C)	
51.	A full ripple fi	wave bridge rectifier is sur requency will be	plied v	oltage at 50 Hz. The lowest	
	(A)	300Hz	(B)	200Hz	
		150Hz		100Hz	
52.	Quantiz	ation noise occurs in			
	(A)	TDM	(B)	PCM	
	(C)	FDM	(D)	WDM	



53.	Which	Which of the following materials find application in MASER?					
	(A) (C)	Ferrimagnetic Ferromagnetic	(B) (D)	Paramagnetic Diamagnetic			
54.	The val	ue of numerical aperture in o	ptical	fibre is			
	(A) (C)	Greater than 1 Equal to 1	(B) (D)	Less than 1 Equal to ∞			
55.		andwidth is needed for an Fl CHz and handles audio signal	10,000	nal that has a peak deviation 200 Hz to 5 KHz?			
	(A) (C)	6 KHz 10 KHz	(B) (D)	9.6 KHz 16 KHz			
56.	In FM,	when frequency deviation do	ubled,	, then			
	(A) (B) (C) (D)	modulation index is decreas modulation index is doubled modulation index halved no change occurs in modula	la:	ndex values			
57.	What is	SIM?					
	(A) (C)	Select Interrupt Mask Set Interrupt Mask	(B) (D)	Sorting Interrupt Mask Start Instruction Mode			
58.	Superpo	osition theorem can be applied	d only	to circuits having			
	(A) (C)	Resistive elements No-linear elements	(B) (D)	Passive elements Linear bilateral elements			
59.	An AM	An AM demodulator can be implemented with					
	<ul> <li>(A) a linear multiplier followed by low pass filter</li> <li>(B) a linear multiplier followed by high-pass filter</li> <li>(C) a diode followed by high pass filter</li> <li>(D) a linear multiplier followed by band-stop filter</li> </ul>						

60.	In a bipolar transistor, stability factor for a fixed bias circuit is given by					
00.	(A) $S = 1/(1+\beta)$ (C) $S = (\beta - 1)^2$	(B) $S = 1/(\beta - 1)$ (D) $S = \beta + 1$				
61.	Phase Lock Loop (PLL) system is us	sed for the detection of				
	(A) PM (C) FM	(B) AM (D) QAM				
62.	Which is the 8086 instruction that w	vill form the 2's complement?				
	(A) ADD (C) NOT	(B) CMP (D) NEG				
63.	LXIH 4000 is an example of					
	<ul><li>(A) Direct addressing mode</li><li>(C) Implied addressing mode</li></ul>	<ul><li>(B) Indirect addressing mode</li><li>(D) Immediate address mode</li></ul>				
64.	The status of flag cannot be	e checked.				
	<ul><li>(A) auxiliary carry</li><li>(C) parity</li></ul>	(B) carry (D) zero				
65.	In 8085, name the 16 bit register					
	<ul><li>(A) Stack pointer</li><li>(C) Both (A) and (B)</li></ul>	<ul><li>(B) Program counter</li><li>(D) Instruction register</li></ul>				
66.	Fetching the next instruction while is known as	le the current instruction is executing				
	<ul><li>(A) DMA</li><li>(C) Parallel processing</li></ul>	<ul><li>(B) Pipelining</li><li>(D) Cache</li></ul>				

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67. Maximum number of I/O devices that can interface with 8085 is			interface with 8085 is				
	(A)	8	(B)	256			
		1024		512			
68.	When a	BJT operates in cut-off					
	(A)	$V_{CE} = 0$	(B)	$V_{CE} = V_{CC}$			
	(C)	V <sub>CE</sub> has negative value		I <sub>C</sub> is maximum			
69.	Companding is used						
	(A) to overcome quantizing noise in PCM						
	(B)	to protect small signals in	PCM fi	om quantizing noise			
	(C)						
	(D) to increase power content of the modulating signal						
70.	A MOSFET is sometimes calledFET.						
	(A)	many gate	(B)	open gate			
		insulated gate	(D)	shorted gate			
71.	The emitter of a transistor is generally doped the heaviest because it						
	(A) has to dissipate maximum power						
	(B)						
	(C)						
	(D) must possess low resistance						
72.	The L	VDT is primarily used for t	he meas	urement of			
	(A)	humidity	(B)	velocity			
	(C)		(D)	displacement			
73.	As a result of introduction of negative feedback which of the following will not decrease?						
	(A)	Bandwidth	(B)				
	(C)		(D)	) Instability			

74.	Which o	of the following material is	used fo	r infrared LEDs?
	(A) (C)		(B) (D)	Calcium Phospide None of the above
75.	Which day and	of the following remains un l night?	affecte	d by changes on accounts of
		Ground wave Tropospheric wave	(B) (D)	
76.				equal surface charge density ne gap between the plates is
	(B)	Zero Same as that produced by of Double of the field produce Infinite		
77.	The ba	sic process that's going on in	nside a l	DSP chip is
		Quantization MAC	(B) (D)	Logarithmic transformation Vector calculation
78.	When amplitu	two sine waves of amplitu ade of the spectral componen	ide A <sub>1</sub> its is	and A2 are multiplied, the
		$\begin{array}{cccccccccccccccccccccccccccccccccccc$		$A_1 A_2/4 A_1 A_2$
79.	Laplac	e transform of teat is		
		$\frac{1}{(s-a)^2}$		$\frac{s}{(s-a)^2}$
	(C)	$\frac{s}{(s-a)}$	(D)	$\frac{s}{(s+a)^2}$

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- m		~		-		
XII	Inverse	/	transform	ort.	3	10
		-	11 11 12 2 2 2 2 2 2 2 2 2 2 2 2 2 2 2	0.2		1.3

0	-	and the same of th	
$i \Delta \lambda$	754	77-	-1
100	147	4.2	2.

 $(B) \quad \delta(n)$ 

(D) u(n)

81. The Fourier Transform of 
$$x(n) = a^n u(n-4)$$
 is

(A) 
$$\frac{a^4 e^{-j4\omega}}{1 - ae^{-j\omega}}$$

 $\frac{a^4}{1 - ae^{-j\alpha}}$ 

(C) 
$$\frac{a^4 e^{-j4\phi}}{2}$$

(D)  $\frac{a^4 e^4}{e^{/a^4}}$ 

82.	Energy	associated	with	function	f(t)	=	e <sup>-t</sup>	u(t)	is
-----	--------	------------	------	----------	------	---	-----------------	------	----

(A) 0

(B) 1/3

(C) 12

(D) 1.4

### 83. Intrinsic impedance of a free space is

(A) 350 Ω

(B) 377 Ω

(C) infinite

(D) zero

(A) perfect dielectric

(B) semi-conductor

(C) conductor

(D) All of the above

(A) 1

(B) 2

(C) x

(D) None of the above

# 86. The following waves do not exist in waveguides

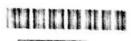
(A) TM waves

(B) TE waves

(C) TEM waves

(D) TE and TM waves

	*		
87.	In a transmission line, the distance minima of a standing wave is	e bet	ween adjacent maxima and
	(A) λ/8 (C) λ/2	(B) (D)	
88.	A transmission line of characteristic The input impedance is	impe	dance $Z_0$ is terminated in $Z_0$ .
	(A) $Z_0/2$ (C) $2 Z_0$	(B) (D)	Z <sub>0</sub> 4 Z <sub>0</sub>
89.	In a broadcast superheterodyne rece	iver, t	he
	<ul> <li>(A) local oscillator operates bel</li> <li>(B) mixer input must be turned</li> <li>(C) local oscillator frequency is</li> <li>(D) RF amplifier normally we frequency</li> </ul>	to the	signal frequency
90.	Entropy is basically a measure of		
	<ul><li>(A) rate of information</li><li>(C) probability of information</li></ul>	(B) (D)	average information disorder of information
91.	Thermal noise power in a resistor F	R is pr	oportional to
	(A) R (C) R <sup>2</sup>	(B) (D)	1/R Independent of R
92.	The skip distance is		
	<ul> <li>(A) independent of frequency</li> <li>(B) independent of the state o</li> <li>(C) independent of transmitting</li> <li>(D) dependent on transmitting</li> </ul>	f ioniz	ver



93.	Spectral	density of white noise		
	(A)	varies with frequency	(B)	is constant
		varies with bandwidth		None of the above
94.	Quadrat	ture multiplexing is a form	of	
	(A)	time division multiplexing	g	
	(B)	frequency division multip	lexing	
	(C)	combined time and freque	ency divi	ision multiplexing
	(D)	None of the above		
95.	In TV,	the contrast is controlled by	Ÿ	
	(A)	DC voltage in video circu	ait	
	(B)	AC voltage in video circu	iit	
	(C)	Both (A) and (B)		
	(D)	None of the above		
96.	ARQ s	tands for		
	$(\mathbf{A})$	Accelerated redirection for	acility	
	(B)	Amplitude ratio detector	quantizii	ng noise
		Automatic repeat request		
	(D)	Aerial range quartz crysta	al	
9	ln a kl	ystron amplifier the input of	avity is	called
	(A)	Buncher		Catcher
	(C)	Pierce gun	(D)	Collector
98	Micro	wave resonators are used in	1	
	(A)	microwave oscillators		

(B) microwave narrow band amplifier
(C) microwave frequency metres
(D) All of the above

99.	In a TW	T the amplitude of resulta	nt wave	travelling down the helix
	(A) (C)	increases exponentially decreases exponentially		increases linearly is almost constant
100.	Which o	of the following is not a tra	avelling v	wave?
	(A) (C)	$e = E_m \sin (\beta x - \omega t)$ $e = E_m \sin (\omega t - \beta x)$	(B) (D)	$e = E_m \cos (\beta x - \omega t)$ $e = E_m \sin (\beta x)$
101.	Which	of the following parameter	s is negli	igible in transmission lines?
	(A) (C)		(B) (D)	L G
102.		agram to show distance ter is called	time hist	ory of electrons in klystron
	(A) (C)	apple gate diagram bunching diagram	(B) (D)	
103.	Which	of the following devices u	ses a slov	w wave structure?
	(A) (B) (C) (D)	Reflex klystron oscillato	plifier	
104.	A wav	eguide section in a microw	ave circu	iit acts as
	(A) (C)	LP filter HP filter	(B) (D)	Band pass filter Band stop filter
105.	freque	a MOD-14 ripple count ency to the counter is 30 ker will be	er using KHz, then	J-K flip-flops. If the clock in the output frequency of the
	(A) (C)		(B) (D)	



106.	Schottky	TTL gates have prop	agation delay	y time of the order of
	(A) (C)		(B) (D)	
107.	A one-to	o-sixteen demultiplexe	er requires	
	(A) (C)	2 select input lines 8 select input lines	(B) (D)	3 select input lines 4 select input lines
108.		imber of states in its ing of 'n' flip-flops can		equence that a ring counter
		2 <sup>n</sup> -1 n	(B) (D)	2 <sup>n-1</sup> 2n+1
109.	In app the OP	lications where measure AMP circuit recomme	rement of a punded is	physical quantity is involved,
*	(A) (B) (C) (D)	a comparator an active filter		
110.	For a	3-bit flash ADC, the m	mber of com	parators required are
		) 5 ) 7	(B) (D)	
111.	The u	nity gain bandwidth of	741 OPAMI	e is typically
	(C	17	(B)	1 MHz
112	The	conversion time of a du	al-slope AD	is typically in the range of
	(A	5 to 10 ns	(B)	10 to 100 ns

113.	. The ratio of change in input offset voltage when var	iation in	supply
	voltage is made, is called		

(A) PSRR

CMRR (B)

(C) transient response

input offset voltage stability (D)

- Removing bypass capacitor across the emitter-leg resistor in a CE 114. amplifier causes
  - increase in current gain (A)

decrease in current gain

increase in voltage gain

(D) decrease in voltage gain

- Hysteresis is desirable in Schmitt-trigger, because 115.
  - energy is to be stored/discharged in parasitic capacitances (A)

effects of temperature would be compensated

- devices in the circuit should be allowed time for saturation (C) and desaturation
- it would prevent noise from causing false triggering
- The important characteristic of emitter-follower is 116.
  - high input impedance and high output impedance (A)
  - high input impedance and low output impedance (B)
  - low input impedance and low output impedance (C)
  - low input impedance and high output impedance (D)
- In class-A amplifier, the output current flows for 117.
  - a part of the cycle or the input signal (A)
  - the full cycle of the input signal (B)
  - half the cycle of the input signal (C)
  - 3/4th of the cycle of the input signal



118.	A phase shift oscillator uses
	<ul> <li>(A) LC tuning</li> <li>(B) Piezo-electric crystal</li> <li>(C) Balanced bridge</li> <li>(D) Variable frequency operation</li> </ul>
119.	Ready pin of a microprocessor is used
	<ul> <li>(A) to indicate that the microprocessor is ready to receive inputs</li> <li>(B) to indicate that the microprocessor is ready to receive outputs</li> <li>(C) to introduce wait states</li> <li>(D) to provide direct memory access</li> </ul>
120.	Itanium processor of Intel is a
	<ul> <li>(A) 32 bit microprocessor</li> <li>(B) 64 bit microprocessor</li> <li>(C) 128 bit microprocessor</li> <li>(D) 256 bit microprocessor</li> </ul>
121.	The PCI bus is the important bus found in all the new Pentium systems because
	(A) it has plug and play characteristics
	<ul> <li>(B) it has ability to function with a 64 bit data bus</li> <li>(C) any Microprocessor can be interfaced to it with PCI controller or bridge</li> <li>(D) All of the above</li> </ul>
122.	In a virtual memory system, the addresses used by the programmer belongs to
	(A) memory space (C) address space (B) physical addresses (D) main memory address
123.	DMA interface unit eliminates the need to use CPU registers to transfer data from
	(A) MAR to MBR (C) I/O units to memory (B) MBR to MAR (D) Memory to I/O units

- 124. Which is true for a typical RISC architecture?
  - (A) Micro programmed control unit
  - (B) Instruction takes multiple clock cycles
  - (C) Have few registers in CPU
  - (D) Emphasis on optimizing instruction pipelines
- 125. CPU checks for an interrupt signal during
  - (A) Starting of last machine cycle
  - (B) Last T-State of instruction cycle
  - (C) First T-State of interrupt cycle
  - (D) Fetch cycle
- 126. Silicon diodes are preferred to Germanium for high temperature operation because
  - (A) doping of silicon is simple process
  - (B) rate of increase of reverse saturation current with temperature is more in case of silicon
  - (C) the reverse saturation current of silicon diodes is smaller than that of germanium
  - (D) silicon diodes can be used to rectify even small voltages
- 127. In an unbiased PN junction the current in equilibrium is
  - (A) zero because no charge cross the junction
  - (B) zero because equal number of charges cross the junction
  - (C) due to diffusion of minority carriers
  - (D) due to diffusion of majority carriers
- 128. In a regulated power supply using a Zener diode the unregulated input voltage as compared to the regulated output voltage must be
  - (A) same

(B) smaller

(C) larger

(D) larger with opposite polarity



#### 129. The diffusion capacitance of PN junction

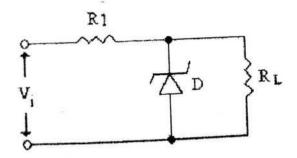
- (A) decreases with increasing current and increasing temperature
- (B) decreases with decreasing current and increasing temperature
- (C) increases with increasing current and increasing temperature
- (D) does not depend on current and temperature

## 130. In an intrinsic semiconductor, the Fermi-level is

- (A) closer to the valence band
- (B) midway between conduction and valence band
- (C) closer to the conduction band
- (D) within the valence band

## 131. In an amplifier with negative feedback

- (A) only the gain of the amplifier is affected
- (B) only the gain and bandwidth of the amplifier are affected
- (C) only the input and output impedances are affected
- (D) All of the four parameters mentioned above would be affected
- 132. In the voltage regulator shown below, if the current through the load decreases,



- (A) the current through R1 will increase.
- (B) the current through R1 will decrease.
- (C) zener diode current will increase.
- (D) zener diode current will decrease

133.	The low	est output impedance is obta	ined i	in case of BJT amplifiers for
		CB configuration CC configuration	(B) (D)	II DT Ction
134.	is 100 a	nplifier with negative feedband it employs a feedback fadetermine voltage gain with	actor o	ne gain of the basic amplifier of 0.02. If the input signal is ack.
	(A)	33.33	(D)	3.33
	(C)		(B)	1.33
	(0)	333.3	(D)	1.55
135.	A BJT Determ		µA ar	nd emitter current of 15mA.
	(A)	590	(B)	5.9
	2. 2	59	(D)	
	(0)		(12.)	13
136.	In gene	eral, the reactance of inductors	s incre	eases with
	(A)	increasing AC frequency	(B)	decreasing AC for
	(C)		(D)	g = - quency
137.	The co	olor of light emitted from the I	ED li	ke GaAs depends on
	(A)	forward bias alone		
	(B)			
		λ of light focused on the did	ode	
		reverse breakdown voltage		
138.	The m	inimum amount of hardware r	equire	ed to make a lowpass filter is
	(A)	a resistance, a capacitance a	nd an	Opamn
	(B)			
	(C)	a resistance and a capacitan	ce	•
	(D)	a resistance, a capacitance a	nd an	inductance
	*			



139.	identical		_	two magnetically coupled, sonance frequency of either
		a peak always either a peak or a dip	(B) (D)	a dip always neither a peak nor a dip
140.		r, resonance condition exists		least one inductor and one when the input impedance of
	(A) (C)	purely resistive finite	(B) (D)	purely reactive infinite
141.		sistances $R_1$ and $R_2$ give comes and 1 ohm when in parallel.		resistance of 4.5 ohms when resistances are
	(A) (C)	3 ohms and 6 ohms 1.5 ohms and 3 ohms	(B) (D)	3 ohms and 9 ohms 1.5 ohms and 0.5 ohms
142.	Solar ce	ells		
	(A) (B) (C) (D)	give high output current of are same as photovoltaic ce both (A) and (B) None of the above	lls	
143.	The rev	verse recovery time of a Scho	ttky d	iode is
	(A) (C)	50ms 50 ns	(B) (D)	50 μs 50 ps
144.	The op	erating state that distinguished	es a SC	CR from a diode is
	(A) (C)	forward conduction state reverse conduction state	(B) (D)	The state of the s

A network N is to be connected to load of 500 ohms. If the equivalent voltage and Norton's equivalent current of N are 10mA respectively, the current through the load will be	e 5Volts and
10mA respectively, the current through the load will be	

(A) 10mA

(B) 5mA

(C) 2.5mA

(D) 1mA

146. A stable system must have

(A) zero or negative real part for poles and zeros.

(B) atleast one pole or zero lying in the right-half s-plane.

(C) positive real part for any pole or zero.

(D) negative real part for all poles and zeros

147. The feedback factor at the frequency of oscillation of a Wien bridge oscillator is

(A) 3

(B) 1/3

(C) 1/29

(D) 3/29

148. If the peak value of the input voltage to a half wave rectifier is 28.28 volts and no filter is used, the maximum dc voltage across the load will be

(A) 20√2V

(B) 15 V

(C) 9 V

(D) 14.14 V

149. A resistor used in colour TV has the following colour bands: yellow, violet, orange and silver. Its nominal value is

(A)  $4.7 \text{ K}\Omega \pm 10 \%$ 

(B)  $4.7 \text{ K}\Omega \pm 5 \%$ 

(C)  $47 \text{ K}\Omega \pm 10 \%$ 

(D)  $470 \text{ K}\Omega \pm 5 \%$ 

150. An ideal voltage source of 12 V provides a current of 150 mA to a load connected across it. If the load impedance is halved, the new load current will be

(A) 0.3 A

(B) 0.15 A

(C) 0.6 A

(D) 1.2 A